Ferromagnetic quantum critical point in URhGe doped with Ru

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Ferromagnetic quantum critical point in URhGe doped with Ru

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(Dated: February 1, 2008) We have investigated the thermal, transport and magnetic properties of URh$_{1-x}$Ru$_x$Ge alloys near the critical concentration $x_{cr} = 0.38$ for the suppression of ferromagnetic order. The Curie temperature vanishes linearly with $x$ and the ordered moment $m_0$ is suppressed in a continuous way. At $x_{cr}$ the specific heat varies as $c \sim T^0$ and the $\gamma$-value $c/T_{\gamma=0}$ is maximum and the temperature exponent of the resistivity $\rho \sim T^n$ attains a minimum value $n = 1.2$. These observations provide evidence for a ferromagnetic quantum phase transition. Interestingly, the coefficient of thermal expansion and the Grüneisen parameter $\Gamma$ remain finite at $x_{cr}$ (down to $T = 1$ K), which is at odds with recent scaling results for a metallic quantum critical point.

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In recent years interest has continued to grow in materials that exhibit a quantum phase transition (QPT), i.e. a transition at zero temperature driven by quantum fluctuations [1]. QPTs are fundamentally different from their classical counter parts at finite $T$, where the transition is due to thermal fluctuations of the order parameter. QPTs can be induced in a wide range of materials, such as correlated metals [2], cuprate superconductors [3], common metals [4] and the two-dimensional electron gas [5]. This is accomplished by adjusting a control parameter (e.g. pressure $p$, doping $x$, magnetic field $B$, or electron density) in order to tune the system to a quantum critical point (QCP). At this point the quantum critical fluctuations give rise to unusual temperature laws (non-Fermi liquid behavior (nFL)) for the magnetic, thermal and transport parameters [5], and new collective states may emerge, e.g. unconventional superconducting [6] or electronic states [7]. This in turn calls for novel concepts and theories [2, 10, 11]. In order to provide a fruitful testing ground, it is important to identify new systems and to investigate their critical behavior.

Strongly correlated electron systems, notably heavy-fermion compounds based on the $f$-elements Ce, Yb or U, are especially suited to study magnetic-to–nonmagnetic QPTs, because the ordering temperatures are low ($\sim 10$ K) and the exchange interaction can be modified relatively easily by an external control parameter. Currently, there are two central questions that are being addressed by studying QPTs in these materials. The first issue is the fate of the quasiparticles when the antiferromagnetic (AF) or ferromagnetic (FM) phase is entered. In the conventional scenario a spin density wave is formed [6] and the quasiparticles preserve their itinerant character (as in CeIn$_{3-x}$Sn$_x$ [12]). Because the itinerant model is unable to account for the nFL behavior in certain materials, an alternative local quantum criticality model has been put forward [2, 10, 11]. Here the quasiparticles (Kondo-screened moments) decompose at the critical point in conduction electrons and local $f$-moments that undergo magnetic order (as in CeCu$_{6-x}$Au$_x$, [2] and YbRh$_2$(Si$_{1-x}$Ge$_x$)$_2$ [13]). The second captivating issue is the emergence of unconventional superconducting (SC) states near the pressure induced QCPs in CePd$_2$Si$_2$, CeIn$_3$ [8] and UGe$_2$ [14]. Evidence is at hand that in these materials unconventional pairing is realized (d-wave pairing for the AF and p-wave pairing for the FM systems). This strongly suggests Cooper pairing mediated by AF or FM spin fluctuations rather than by phonons. The coexistence of FM order and SC in UGe$_2$ (and possibly in UIr [15]) under pressure, is uncommon in nature and attracts much attention.

In this paper we provide evidence for a ferromagnetic QPT in URhGe doped with Ru. Our research is motivated by the unique properties of the parent compound UrhGe at ambient pressure: (i) SC below $T_c = 0.25$ K coexists with itinerant FM order (Curie temperature $T_C = 9.5$ K) [10], and (ii) re-entrant SC is induced by applying a large magnetic field ($B \sim 12$ T) [17]. These observations immediately prompted the question whether one can tune URhGe to a FM QCP by mechanical or chemical pressure, with the objective to probe the quantum critical fluctuations and possibly link these to the SC pairing mechanism. Resistivity measurements under hydrostatic pressure, however, revealed that $T_C$ increases at a rate of 0.065 K/kbar [18]. Also, upon the application of uniaxial pressure $T_C$ increases as was extracted from the Ehrenfest relation [19]. As regards to chemical pressure, best candidate dopants are Ru and Co, since among the neighboring isostructural UTX compounds (T = transition metal and X = Ge or Si) only UruGe and UCoGe have a paramagnetic ground state [20, 21]. Indeed, FM order in URhGe can be suppressed by replacing Rh by Ru and vanishes at 38 at. % Ru [22, 23]. Here we investigate the thermal, transport and magnetic...
properties of $\text{URh}_{1-x}\text{Ru}_x\text{Ge}$ alloys near the critical concentration $x_{cr} = 0.38$. The observed nFL $T$ dependencies of the specific heat and electrical resistivity, together with the smooth suppression of the ordered moment, provide evidence for a continuous FM QPT. This classifies $\text{URh}_{1-x}\text{Ru}_x\text{Ge}$ as one of the scarce $f$-electron systems in which a FM QCP can be reached by doping (a FM QPT was also reported for $\text{CePdI}_{1-x}\text{Rh}_x$ [24], but here the transition is "smeared").

Polycrystalline $\text{URh}_{1-x}\text{Ru}_x\text{Ge}$ samples with $0.0 \leq x \leq 0.60$ were prepared by arc-melting the constituents U, Rh, Ru (all 3N) and Ge (5N) under a high-purity argon atmosphere in a water-cooled copper crucible. The as-cast samples were wrapped in Ta foil and annealed under high vacuum in quartz tubes for 10 days at 875 °C. Samples were cut by spark-erosion. Electron probe micro-analysis showed the single phase nature of the samples within the resolution of 2%. X-ray powder diffraction confirmed the orthorhombic TiNiSi structure (space group Pnma) [25, 26]. Upon substituting Ru the unit cell volume $\Omega = 224.3 \AA^3$ of $\text{URhGe}$ decreases linearly at a rate of 0.067 $\AA^3$ per at.% Ru (i.e. $\Delta \Omega = 1.1\%$ at $x_{cr}$) in an anisotropic way, the main effect being the reduction of the $a$ lattice parameter [23].

The specific heat $c(T)$ was measured down to 0.4 K using a semi-adiabatic method in a home-built $^3\text{He}$ system. Electrical resistivity $\rho(T)$ data were collected in a commercial $^3\text{He}$ system (Heliox - Oxford Instruments, $T \geq 0.25$ K) using a low frequency ac-resistance bridge. The thermal expansion $\alpha(T)$ was measured using a parallel-plate capacitance dilatometer in the $T$ range 1-15 K. The dc magnetization $M(T)$ ($T \geq 1.8$ K) was obtained using a Quantum Design SQUID magnetometer. Temperature scans in magnetic fields $B$ up to 5 T were made after field cooling.

The overall effect of Ru doping on ferromagnetism in $\text{URhGe}$ is presented in Fig.1, where we have plotted the $f$-electron specific heat $c_m$, obtained after subtracting the lattice contribution ($c_{lat} = \beta T^3$ for $T \leq 20$ K with $\beta = 0.60 \times 10^{-3}$ J/molK$^4$ [23]), as $c_m/T$ vs $\log T$ for $0 \leq x \leq 0.50$. Upon doping, $T_C$ initially increases, but for $x \geq 0.10$ the ordering peak shifts towards lower $T$ and weakens. Values of $T_C(x)$, identified by the inflection points in $c/T$ vs $T$ (on a linear $T$ scale) at the high $T$ side of the peaks, are traced in Fig.2a and are in excellent agreement with the values determined from $M(T)$ and $\rho(T)$ [22]. For $x \geq 0.20 T_C$ decreases linearly with $x$ at a rate of 0.45 K/at.% Ru. For $x = 0$ the magnetic specific heat for $T \leq 5$ K is described by $c_m(T) = \gamma T + \delta T^{3/2}$, where $\gamma$ is the linear coefficient of the electronic specific heat and the second term is the spin wave contribution [27]. The values for $\gamma$ and $\delta$ extracted by fitting the data (see Fig.1) are in good agreement with the values reported in Ref. [24]. Upon doping Ru an energy gap $\Delta$ opens in the magnon spectrum and the specific heat for $x = 0.05$ and 0.10 now follows the relation ($T \leq 5$ K)

$$c_m(T) = \gamma T + \delta T^{3/2} e^{-\Delta/k_B T}$$

(see fits in Fig.1). The most important result of our specific heat experiments however is the pronounced $c_m(T) = -bT \ln(T/T_0)$ dependence for $x_{cr}$, where $b = 0.062$ J/molK$^2$ and $T_0 = 41$ K. This nFL term is observed over one and a half decade in $T$ (0.5 - 9 K). At $x_{cr}$, $c/T |_{0.5K}(x)$ has a maximum (Fig.2c). The total $f$-electron entropy obtained by integrating $c_m/T$ vs $T$ between 0.5 and $\sim 15$ K amounts to $\sim 0.48 R \ln 2$ for $x = 0$ and decreases to 0.33R ln2 at $x_{cr}$. Its small value confirms the itinerant nature of the FM transition (the ordered moment $m_0$ is 0.4 $\mu_B$ for $x = 0$ [10, 25]).

The electrical resistivity of $\text{URh}_{1-x}\text{Ru}_x\text{Ge}$ ($x \leq 0.60$) at high $T$ [24] shows the behavior typical for a FM Kondo-lattice. The data for $x = 0.38$ are shown in the inset in Fig.3, where the maximum near 130 K signals the formation of the Kondo-lattice. For the FM compounds at low $T$ a kink in $\rho(T)$ (and maximum in $d\rho(T)/dT$) marks $T_C$. For all doped samples the total resistivity drop in the $T$ interval 0-300 K is $\sim 150-250 \mu\Omega cm$, which is usual for uranium intermetallics [21]. However, the residual resistivity values $\rho_0$ are large ($\sim 200-300 \mu\Omega cm$), which is due to the brittleness of the samples (cracks). Consequently, the RRR values ($R(300K)/R(0K)$) are small ($\sim 2$). In Fig.3 we show $\rho(T)$ at low $T$ for $0.10 \leq x \leq 0.60$. For a FM with gapped magnon modes $\rho(T) = \rho_0 + AT^n + B T^2 \Delta e^{-\Delta/k_B T} (1 + 2k_B T/\Delta)$ [28], where the 2nd term is the electron-electron scattering term (i.e. the FL term when $n = 2$) and the 3rd term yields the scattering from magnons. For $x = 0.10$ and 0.20 fits reveal that the 2nd term is dominant ($A \gg B$) and $\rho(T) \sim T^{2.0 \pm 0.1}$ over a wide $T$ range in the FM state.
in three orthogonal directions on the polycrystalline sample and we restrict the analysis to fitting \( \rho(T) \) (see Fig.3). Therefore, we conclude that scattering from magnons can be neglected in our polycrystalline samples and we restrict the analysis to fitting \( \rho(T) = \rho_0 + AT^n \) (see Fig.3). The values of \( n \) extracted (by taking the best fit over the largest \( T \) interval) are shown in Fig.2c. \( n(x) \) attains a minimum value \( n = 1.2 \) at \( x_{cr} \), followed by a slow recovery to the FL value \( n = 2 \) there above.

The magnetization \( M(T) \) for all samples was measured in \( B = 0.01 \) T and 1 T down to 1.8 K. In addition \( M(B) \) was measured at fixed \( T \) in order to produce Arrott plots \( (M^2 \text{ vs } B/M) \). \( M_{[2K]} \)-values are traced in Fig.2b. For pure URhGe \( M_{[2K]} \) in 1 T \( \simeq 0.2 \mu_B \) in agreement with the polycrystalline average \( m_0 \) for a uniaxial FM \( (m_0 = 0.4 \mu_B \text{ directed along the } c\text{-axis}) \). In 0.01 T a reduced value \( M_{[2K]} \simeq 0.11 \mu_B \) is observed due to demagnetizing effects. Values of \( T_C \) (Fig.2a) were determined from the inflection points in \( M(T) \) in 0.01 T and from the Arrott plots. For \( x \geq 0.38 \) the Arrott plots \( (T \geq 1.8 \text{ K}) \) no longer indicate magnetic order (see inset in Fig.2b for \( x = 0.38 \)). A most important feature of the data is the gradual decrease of \( M_{[2K]}(x) \). For \( B = 0.01 \) T \( M_{[2K]}(x) \) smoothly goes to 0 at \( x = 0.35 \) \( (T_C = 1.3 \pm 0.1 \text{ K}) \), while for \( B = 1 \) T a finite field induced \( M_{[2K]} \) remains. We conclude that the FM-paramagnetic transition as a function of \( x \) is a continuous (2nd order) phase transition.

In Fig.4 we show the coefficient of volume thermal expansion \( \beta(T) \) for \( x_{cr} = 0.38 \) at \( T \geq 1 \text{ K} \). The data (solid line) is obtained by averaging \( \alpha_i(T) \) measured for three orthogonal directions on the polycrystalline sample \( (\beta = \Sigma_i \alpha_i) \) in order to eliminate possible anisotropy effects due to crystallites with preferred orientations. The \( T \) dependence of \( \beta \) at low \( T \) is weaker than that of the specific heat (see Fig.4). Concurrently, the Grüneisen ratio \( \Gamma = V_m \beta/\kappa c \) decreases below \( T \simeq 7 \text{ K} \) (here the molar volume \( V_m = 3.36 \times 10^{-5} \text{ m}^3/\text{mol} \) and isothermal compressibility \( \kappa \simeq 10^{11} \text{ Pa}^{-1} \)). The quasi-linear behavior of \( \Gamma(T) \) for \( 1 \text{ K} \leq T \leq 5 \text{ K} \) suggests an unusual \( T \) variation of \( \beta \), i.e., roughly proportional to \( T^2 \ln T \).

Having documented the critical behavior of the URh\( _{1-x} \)Ru\( _x \)Ge alloys we conclude that our \( c(T), \rho(T) \) and \( M(T) \) data provide evidence for a continuous FM

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**FIG. 2:** (a) Curie temperature of URh\( _{1-x} \)Ru\( _x \)Ge determined from \( c(T) \) (▲), \( \rho(T) \) (●) and \( M(T) \) (★). The critical Ru content is \( x_{cr} = 0.38 \) (vertical dashed line). (b) Magnetization \( M \) at 2 K in \( B = 0.01 \) (●) and 1 T (○). Inset: Arrott plot for \( x = 0.38 \) at 1.8 K \( \leq T \leq 6 \text{ K} \) (●). \( x/T = 0.5 \text{ K} \) (■) and the exponent \( n \) (□) of \( \rho \sim T^n \). The horizontal dashed line indicates \( n = 2 \).

**FIG. 3:** Resistivity of URh\( _{1-x} \)Ru\( _x \)Ge for \( 0.1 \leq x \leq 0.60 \). The bar gives the absolute scale. The arrows for \( x = 0.30 \) and 0.35 indicate \( T_C \) obtained from additional data sets. The solid lines are fits to \( \rho(T) = \rho_0 + A T^n \). For \( x \leq 0.3 \) \( n = 2.0 \pm 0.1 \). For \( x_{cr} = 0.38 \) \( n = 1.2 \) is minimum. Inset: Resistivity for \( x = 0.38 \) up to 300 K.

**FIG. 4:** Coefficient of volume thermal expansion \( \beta(T) \) (solid line) and specific heat \( c(T) \) (●) of URh\( _{0.62} \)Ru\( _{0.38} \)Ge. Inset: Grüneisen ratio \( \Gamma \) as a function of \( T \).
QPT with $x_{cr} = 0.38$. The most compelling evidence is the specific heat $c_{cr} \sim T \ln(T/T_0)$ observed over one and a half decade in $T$ (Fig.1) [2] and the concomitant maximum in $c/T\vert_{0.5K}(x)$ (Fig.2c). The temperature $T_0 = 41$ K is large, which indicates that our $c(T)$ experiments down to $T = 0.4$ K ($T/T_0 \simeq 0.01$) indeed probe the quantum critical regime. It will be interesting to investigate whether the $c/T \sim \ln T$ behavior persists even at lower $T$. Eventually, however, $c/T$ will saturate because of crystallographic disorder inherent to the URh$_{1-x}$Ru$_x$Ge alloys. Further support for a QCP is provided by the critical behavior in the resistivity $\rho_{cr} \sim T^{1.2}$ up to 2 K. The exponent $n(x)$ has a pronounced minimum at $x_{cr}$ (Fig.2c). The value $n = 1.2$ is smaller than the value $n = 5/3$ predicted for a clean FM QCP [29]. This is not unexpected as disorder reduces $n$ [30]. The itinerant nature of the FM state and the smooth suppression of $m_0$ pointing to a continuous phase transition, strongly suggest that the QPT in URh$_{1-x}$Ru$_x$Ge is of the Hertz-Millis type [6, 7], albeit with modified exponents due to the effects of doping (notably emptying the $d$-band and alloy disorder). For instance, for an itinerant clean FM QPT one expects $T_C \sim (x_c - x)^{d/4}$ (dimension $d = 3$, dynamical critical exponent $z = 3$), while we obtain $T_C \sim (x_c - x)$ over a wide range $0.20 \leq x \leq 0.35$. Deviations from the clean behavior are also observed in $f$-electron materials with a pressure induced continuous FM QPT, like CeSi$_{1.81}$ [31]. On the other hand, for $d$-electron alloys with a continuous FM QPT (e.g. Ni$_x$Pd$_{1-x}$ [32] and Zr$_{1-x}$Nb$_2$Zr$_2$ [33]) the data are to a large extent in agreement with the itinerant model. Further theoretical work is required to clarify these issues.

Finally, we discuss our results for the thermal expansion and the Grüneisen parameter. The finite $\Gamma$-value at low $T$ is in variance with the recent prediction of a diverging Grüneisen ratio $\Gamma \sim T^{-1/2}$ at the QCP ($\nu$ is the correlation length exponent) [34]. For the case of an itinerant FM QCP the scaling results are $\beta_{cr} \sim T^{1/3}$ and $c_{cr} \sim T \log(1/T)$, whence $\Gamma_{cr} \sim \beta_{cr}/c_{cr} \sim (T^{2/3} \log(1/T))^{-1}$ [34]. While the specific heat follows the expected behavior, the thermal expansion clearly does not ($\beta \sim T^2 \ln T$ for $1 \text{ K} \leq T \leq 5$ K). With the value $T_0 = 41$ K extracted from $c_{cr}$, we calculate that $\Gamma_{cr}$ within the scenario of Ref. [34] should have a minimum near 8 K and diverge at lower $T$. This is obviously not the case experimentally (Fig.4). The only other system for which the Grüneisen ratio near a FM QPT has been investigated so far is CePd$_{1-x}$Rh$_x$ [35]. In this system a non-diverging ($T$-independent) $\Gamma$ was also observed in the critical regime.

In conclusion, we have investigated the thermal, transport and magnetic properties of URh$_{1-x}$Ru$_x$Ge near the critical concentration for the suppression of FM order. At $x_{cr} = 0.38$ $c \sim T \ln T$, the $\gamma$-value $c/T\vert_{0.5K}$ has a maximum and the $T$ exponent in the resistivity assumes the nFL value $n = 1.2$. Together with the gradual suppression of the ordered moment $m_0$ the data provide evidence for a continuous FM quantum phase transition.

This offers the sole opportunity thus far to investigate FM spin fluctuations in URhGe under quantum critical conditions. The identification of the FM QCP at ambient pressure in URhGe doped with Ru paves the road to a host of experiments on this unique material.

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